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Product: Bridge Rectifiers (In Line)

Bridge Rectifiers are key devices in many applications where a rectifier signal is required as Input voltage. Linear Power Supplies, SMPS, Battery Chargers, Electronic Ballast... are some applications where they are used.

Manufactured using HYPERRECTIFIER® technology, we offer these devices in several different packages: SMD, Dual In Line, Round, In Line and Square Power.

Product	Family	$I_{F(AV)}$ (A)	I_{FSM} (A)	V_{RRM} (V)	V_F (V)	OUTLINE
FBI15M1M1	FBI15-1M1	15.0	200	1000	1.1	In Line medium



15 Amp. Glass Passivated Bridge Rectifier

<p>Dimensions in mm.</p> <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>L</th> <th>suffix</th> </tr> </thead> <tbody> <tr> <td>17.5</td> <td></td> </tr> <tr> <td>8</td> <td>-4</td> </tr> </tbody> </table> <p>• Mounting Instructions</p> <ul style="list-style-type: none"> • High temperature soldering guaranteed: 260 °C – 10 sc. • Recommended mounting torque: 8 Kg.cm. 	L	suffix	17.5		8	-4	<p>Plastic Case</p>	<p>Voltage 50 to 1000V.</p> <p>Current 15 A.</p>
L	suffix							
17.5								
8	-4							
<ul style="list-style-type: none"> • Glass Passivated Junction Chips. • UL recognized under component index file number E320541. • Lead and polarity identifications. • Case: Molded Plastic. • Ideal for printed circuit board (P.C.B.). • High surge current capability. • The plastic material carries U/L recognition 94 V-O. 								

Maximum Ratings, according to IEC publication No. 134

		FBI15A 1M1	FBI15B 1M1	FBI15D 1M1	FBI15G 1M1	FBI15J 1M1	FBI15K 1M1	FBI15M 1M1
V_{RRM}	Peak recurrent reverse voltage (V)	50	100	200	400	600	800	1000
V_{RMS}	Maximum RMS voltage (V)	35	70	140	280	420	560	700
$I_{F(AV)}$	Max. Average forward current with heatsink without heatsink	15.0 A at 75 °C 3.2 A at 25 °C						
I_{FSM}	10 ms. peak forward surge current (Jedec Method)	200 A						
I^2t	Current squared time (rating for fusing) (1ms.<t<10ms. Tc = 25°C)	110 A ² sec						
V_{DIS}	Dielectric strength (terminals to case, AC 1 min.)	2500 V						
T_j	Operating temperature range	- 55 to + 150 °C						
T_{stg}	Storage temperature range	- 55 to + 150 °C						

Electrical Characteristics at Tamb = 25°C

V_F	Max. forward voltage drop per diode at $I_F = 7.5 A$	1.10V
I_R	Max. instantaneous reverse current at V_{RRM}	5μ A
$R_{th(j-c)}$	Junction-Case. With Heatsink.	2.2 °C/W
$R_{th(j-a)}$	Junction-Ambient. Without Heatsink.	22 °C/W